MOSFET – Single, N-Channel, Small Signal, XDFN3, 0.62 x 0.42 x 0.4 mm 20 V, 220 mA

• Low Profile Ultra Small Package, XDFN3 (0.62 x 0.42 x 0.4 mm)

• These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS



ON Semiconductor®

www.onsemi.com

V _{(BR)DSS}	R _{DS(on)} MAX	I _D Max
	1.5 Ω @ 4.5 V	
20 V	1.8 Ω @ 3.3 V	
	2.2 Ω @ 2.5 V	220 mA
	3.3 Ω @ 1.8 V	
	5.0 Ω @ 1.5 V	

Compliant Applications

• 1.5 V Gate Drive

Features

- Small Signal Load Switch
- High Speed Interfacing
- Level Shift

MAXIMUM RATINGS (T_J = 25° C unless otherwise stated)

for Extremely Space-Constrained Applications

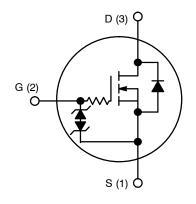
Para	Parameter			Value	Unit	
Drain-to-Source Voltage			V _{DSS}	20	V	
Gate-to-Source Volta	Gate-to-Source Voltage			±8	V	
Continuous Drain	Steady	$T_A = 25^{\circ}C$	Ι _D	220	mA	
Current (Note 1)	State	$T_A = 85^{\circ}C$		158		
	t ≤ 5 s	$T_A = 25^{\circ}C$		253		
Power Dissipation (Note 1)	Steady State	$T_A = 25^{\circ}C$	PD	125	mW	
	t ≤ 5 s			166		
Pulsed Drain Current	t _p = 10 μs		I _{DM}	846	mA	
Operating Junction and Storage Temperature			T _J , T _{STG}	–55 to 150	°C	
Source Current (Body Diode) (Note 2)			۱ _S	200	mA	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		ΤL	260	°C		
0						

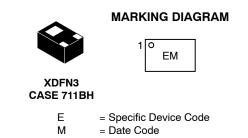
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface-mounted on FR4 board using the minimum recommended pad size, or 2 mm², 1 oz Cu.

2. Pulse Test: pulse width \leq 300 μ s, duty cycle \leq 2%

N-CHANNEL MOSFET





ORDERING INFORMATION

Device	Package	Shipping [†]
NTNS1K5N021ZTCG	XDFN3 (Pb-Free)	8000 / Tape & Reel

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Мах	Unit	
Junction-to-Ambient - Steady State (Note 3)		998	°C ///	
Junction-to-Ambient – t \leq 5 s (Note 3)	R_{\thetaJA}	751	°C/W	

3. Surface-mounted on FR4 board using the minimum recommended pad size, or 2 mm², 1 oz Cu.

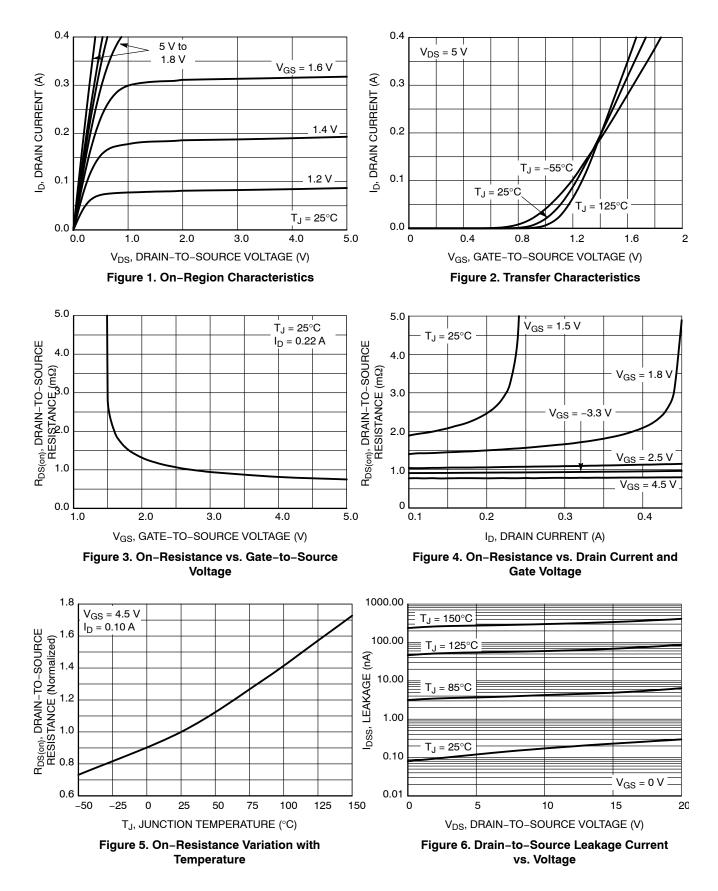
ELECTRICAL CHARACTERISTICS (T_J = $25^{\circ}C$ unless otherwise stated)

Parameter	Symbol	Test Conditio	n	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•						
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = 250 μ A		20			V
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V, V_{DS} = 5 V$	$T_J = 25^{\circ}C$			50	nA
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V, V_{DS} = 16 V$	$T_J = 25^{\circ}C$			100	nA
Gate-to-Source Leakage Current	I _{GSS}	V_{DS} = 0 V, V_{GS} =	±5 V			±100	nA
ON CHARACTERISTICS (Note 4)		-					
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 2$	50 μΑ	0.4		1.0	V
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 1	√, I _D = 100 mA		0.8	1.5	Ω
		V _{GS} = 3.3 V, I _D = 100 mA			1.0	1.8	
		V_{GS} = 2.5 V, I _D = 50 mA			1.1	2.0	
		V _{GS} = 1.8 V, I _D = 20 mA			1.4	3.0	
		V _{GS} = 1.5 V, I _D = 10 mA			1.8	4.5	
Forward Transconductance	9 FS	V _{DS} = 5 V, I _D = 125 mA			0.48		S
Source-Drain Diode Voltage	V _{SD}	V _{GS} = 0 V, I _S = 10 mA			0.6	1.0	V
CHARGES & CAPACITANCES					•		
Input Capacitance	C _{ISS}	V_{GS} = 0 V, freq = 1 MHz, V_{DS} = 15 V			12.3		
Output Capacitance	C _{OSS}				3.4		pF
Reverse Transfer Capacitance	C _{RSS}				2.5		
SWITCHING CHARACTERISTICS, VGS	= 4.5 V (Note	4)			•	•	-
Turn–On Delay Time	t _{d(ON)}				16.5		
Rise Time	t.				25.5		

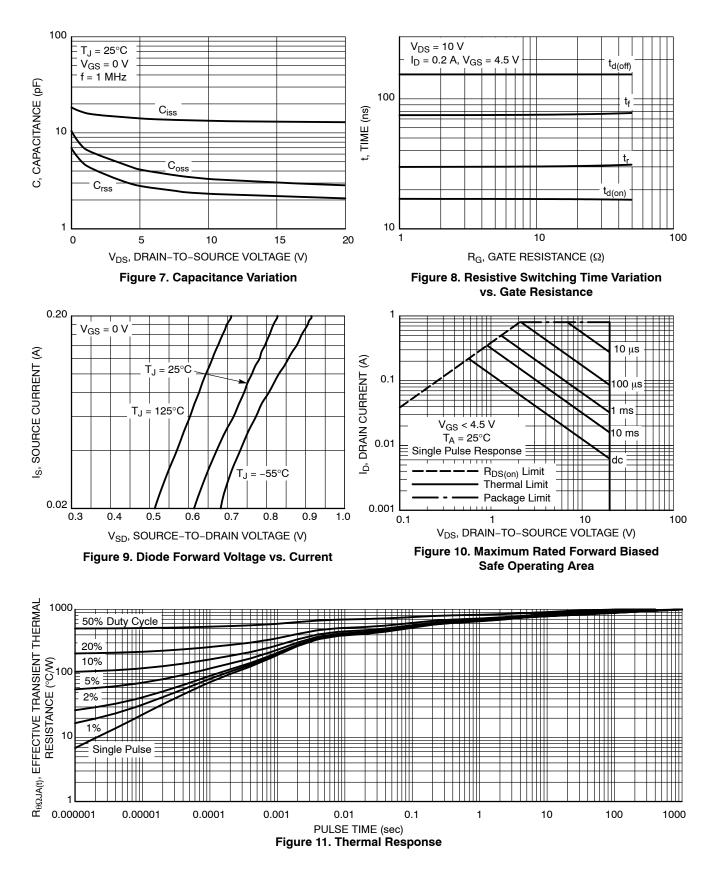
rum on belay nine	۲d(ON)		10.0	
Rise Time	t _r	V _{GS} = 4.5 V, V _{DD} = 15 V,	25.5	20
Turn-Off Delay Time	t _{d(OFF)}	I_D = 200 mA, R_G = 2 Ω	142	ns
Fall Time	t _f		80	

4. Switching characteristics are independent of operating junction temperatures

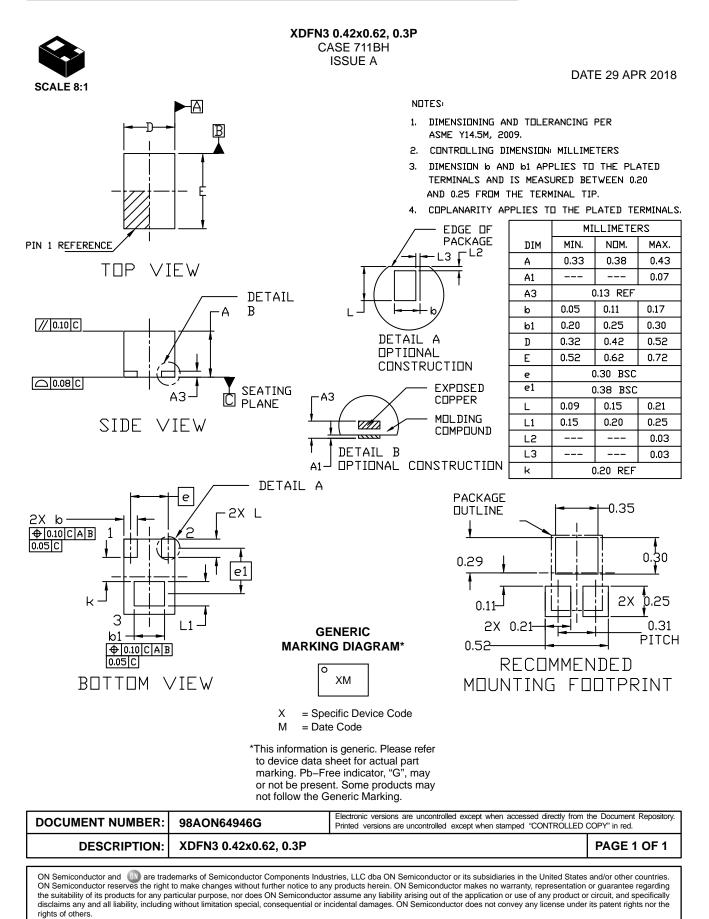
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS







onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters, including "Typicals" must be validated for each customer applications by customer's technical experts. onsemi does not cust performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application or autorized for use as a critical component in life support systems or any CDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any divide for indirectly, any claim of personal injury or death associated with such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and is officers, employees, subsidiaries, and expenses, and expenses, and exponses hard snegges that onsemi was negligent regarding the design or unauthorized use ever if such claim alleges that onsemi was negligent regarding the design or manufacture of the part. Onsemi is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright have and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Email Requests to: orderlit@onsemi.com

TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

 \Diamond